

5-V Low-Drop Fixed Voltage Regulator

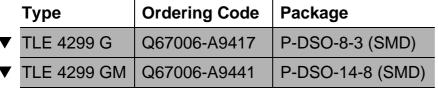
TLE 4299

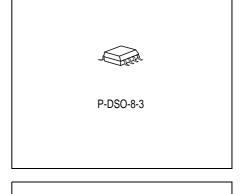
Data Sheet

Features

- Output voltage 5 V ± 2%
- 150 mA Output current
- Extreme low current consumption typical 65 μA in ON state
- Inhibit function: Below 1 μA current consumption in off mode
- Early warning
- Reset output low down to $V_{\rm O}$ = 1 V
- Adjustable reset threshold
- Overtemperature protection
- Reverse polarity proof
- Wide temperature range

	Туре	Ordering Code	Package			
▼	TLE 4299 G	Q67006-A9417	P-DSO-8-3 (SMD)			
▼	TLE 4299 GM	Q67006-A9441	P-DSO-14-8 (SMD)			







▼ New type

Functional Description

The TLE 4299 is a monolithic voltage regulator with fixed 5-V output, supplying loads up to 150 mA. It is especially designed for applications that may not be powered down while the motor is off. It only needs a quiescent current of typical 65 µA. In addition the TLE 4299 GM includes an inhibit function. When the inhibit signal is removed, the device is switched off and the quiescent current is less than 1 µA. To achieve proper operation of the μ-controller, the device supplies a reset signal. The reset delay time is selected application-specific by an external delay capacitor. The reset threshold is adjustable. An early warning signal supervises the voltage at pin SI. The TLE 4299 is pin-compatible to the TLE 4269 and functional similar with the additional inhibit function. The TLE 4299 is designed to supply microcontroller systems even under automotive environment conditions. Therefore it is protected against overload, short circuit and over temperature.



Circuit Description

The TLE 4299 is a PNP based very low drop linear voltage regular. It regulates the output voltage to $V_{\rm Q}$ = 5 V for an input voltage range of 5.5 V $\leq V_{\rm I} \leq$ 45 V. The control circuit protects the device against potential caused by damages overcurrent and overtemperature.

The internal control circuit achieves a 5 V output voltage with a tolerance of \pm 2%.

The device includes a power on reset and an under voltage reset function with adjustable reset delay time and adjustable reset switching threshold as well as a sense control/early warning function. The device includes an inhibit function to disable it when the ECU is not used for example while the motor is off.

The reset logic compares the output voltage $V_{\rm Q}$ to an internal threshold. If the output voltage drops below this level, the external reset delay capacitor $C_{\rm D}$ is discharged. When $V_{\rm D}$ is lower than $V_{\rm LD}$, the reset output RO is switched Low. If the output voltage drop is very short, the $V_{\rm LD}$ level is not reached and no reset-signal is asserted. This feature avoids resets at short negative spikes at the output voltage e.g. caused by load changes.

As soon as the output voltage is more positive than the reset threshold, the delay capacitor is charged with constant current. When the voltage reaches $V_{\rm UD}$ the reset output RO is set High again.

The reset threshold is either the internal defined $V_{\rm RT}$ voltage (typical 4.6 V) or can be lowered by a voltage level at the RADJ input down to 3.5 V. The reset delay time and the reset reaction time are defined by the external capacitor $C_{\rm D}$. The reset function is active down to $V_{\rm I}$ = 1 V.

In addition to the normal reset function, the device gives an early warning. When the SI voltage drops below $V_{\rm SI,low}$, the devices asserts the SI output Low to indicate the logic and the μ -processor that this voltage has dropped. The sense function uses a hysteresis: When the SI-voltage reaches the $V_{\rm SI,high}$ level, SO is set high again. This feature can be used as early warning function to notice the μ -controller about a battery voltage drop and a possible reset in a short time. Of cause also any other voltage can be observed by this feature.

The user defines the threshold by the resistor-values $R_{\rm SI1}$ and $R_{\rm SI2}$.

For the exact timing and calculation of the reset and sense timing and thresholds, please refer to the application section.

Data Sheet Rev. 1.0 2 2002-01-17



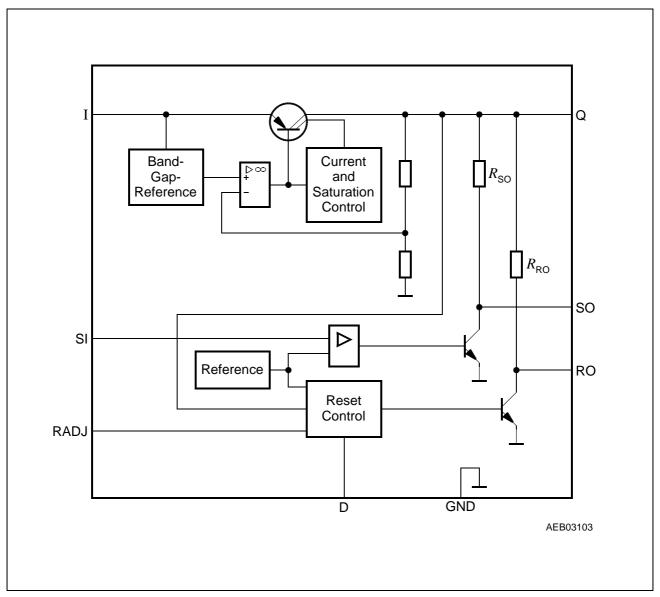


Figure 1 Block Diagram TLE 4299 G



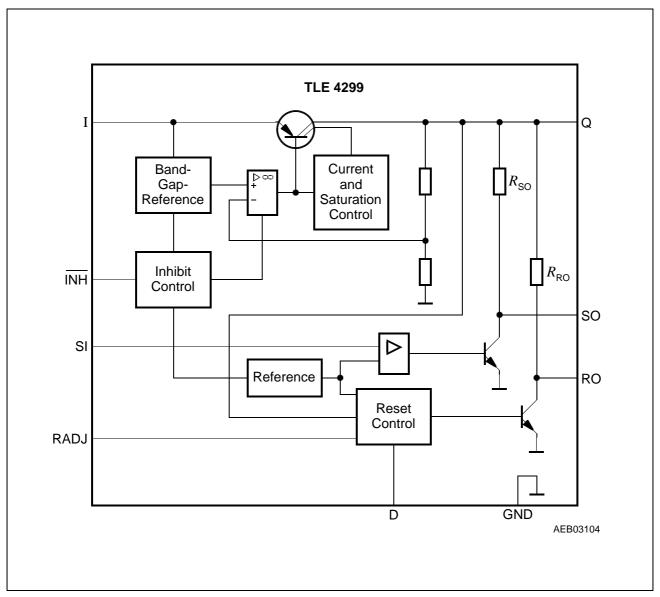


Figure 2 Block Diagram TLE 4299 GM



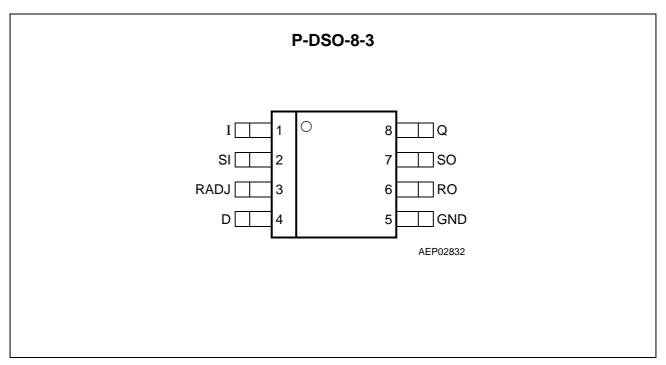


Figure 3 Pin Configuration (top view)

Pin Definitions and Functions (TLE 4299 G)

Pin No.	Symbol	Function
1	I	Input; block directly to GND on the IC with a ceramic capacitor.
2	SI	Sense Input; if not needed connect to Q.
3	RADJ	Reset Threshold; if not needed connect to GND.
4	D	Reset Delay ; to select delay time, connect to GND via external capacitor.
5	GND	Ground
6	RO	Reset Output ; the open-collector output is internally linked to Q via a 20 k Ω pull-up resistor. Keep open, if the pin is not needed.
7	SO	Sense Output; the open-collector output is internally linked to the output via a 20 k Ω pull-up resistor. Keep open, if the pin is not needed.
8	Q	5-V Output; connect to GND with a 22 μ F capacitor, ESR < 5 Ω .



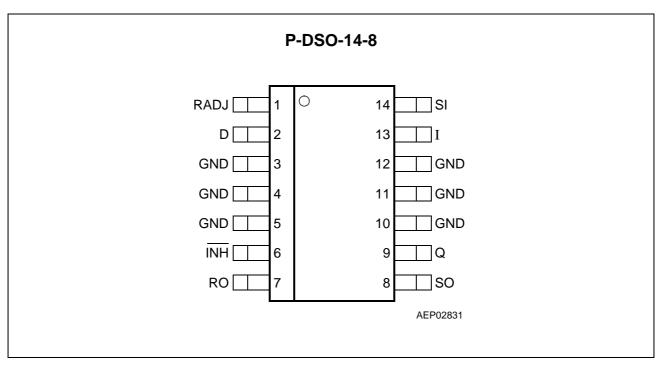


Figure 4 Pin Configuration (top view)

Pin Definitions and Functions (TLE 4299 GM)

Pin No.	Symbol	Function
1	RADJ	Reset Threshold; if not needed connect to GND.
2	D	Reset Delay; connect to GND via external delay capacitor for setting delay time.
3, 4, 5	GND	Ground
6	ĪNH	Inhibit; If not needed connect to input pin I; a high signal switches the regulator ON.
7	RO	Reset Output; open-collector output, internally connected to Q via a pull-up resistor of 20 k Ω . Keep open, if the pin is not needed.
8	SO	Sense Output; open-collector output, internally connected to Q via a 20 k Ω pull-up resistor. Keep open, if the pin is not needed.
9	Q	5-V Output; connect to GND with a 22 μF capacitor, ESR < 5 Ω .
10, 11, 12	GND	Ground
13	I	Input; block to GND directly at the IC by a ceramic capacitor.
14	SI	Sense Input; if not needed connect to Q.



Absolute Maximum Ratings

 $T_{\rm i} = -40 \text{ to } 150 \,^{\circ}\text{C}$

1				
Symbol	Limi	t Values	Unit	Notes
	min.	max.		
V_{I}	- 40	45	V	_
$V_{\overline{INH}}$	- 40	45	V	_
V_{SI}	- 0.3	45	V	_
I_{SI}	1	1	mA	_
DJ				
V_{RE}	- 0.3	7	V	_
I_{RE}	- 10	10	mA	
V_{D}	- 0.3	7	V	_
V_{R}	- 0.3	7	V	_
V_{SO}	- 0.3	7	V	_
V_{Q}	- 0.3	7	V	
$I_{\rm O}$	- 5	_	mA	_
	$egin{array}{c c} V_{ m I} & & & & & & & & & & & & & & & & & & $	min. $V_{\rm I}$ -40 $V_{\rm SI}$ -0.3 $I_{\rm SI}$ 1 DJ $V_{\rm RE}$ -0.3 $I_{\rm RE}$ -10 $V_{\rm D}$ -0.3 $V_{\rm R}$ -0.3 $V_{\rm SO}$ -0.3 $V_{\rm Q}$ -0.3	$V_{\rm I}$ -40 45 $V_{\rm INH}$ -40 45 $V_{\rm SI}$ -0.3 45 $I_{\rm SI}$ 1 1 DJ $V_{\rm RE}$ -0.3 7 $I_{\rm RE}$ -10 10 $V_{\rm D}$ -0.3 7 $V_{\rm R}$ -0.3 7 $V_{\rm SO}$ -0.3 7 $V_{\rm Q}$ -0.3 7	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$



Absolute Maximum Ratings (cont'd)

 $T_{\rm i}$ = -40 to 150 °C

Parameter	Symbol	Limi	t Values	Unit	Notes	
		min.	max.			
Temperature						
Junction temperature	$T_{\rm j}$	_	150	°C	_	
Storage temperature	T_{Stg}	- 50	150	°C	_	

Operating Range

Input voltage	V_{I}	_	45	V	_
Junction temperature	T_{j}	- 40	150	°C	_

Thermal Data

Junction-ambient	R_{thja}	_	200 70	K/W K/W	P-DSO-8-3 P-DSO-14-8
Junction-pin	R_{thjp}	_	60 30	K/W K/W	P-DSO-8-3 P-DSO-14-8 ¹⁾

¹⁾ Measured to pin 4.

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

In the operating range, the functions given in the circuit description are fulfilled.

Data Sheet Rev. 1.0 8 2002-01-17



Characteristics

 $V_{\rm I}$ = 13.5 V; $T_{\rm j}$ = - 40 °C < $T_{\rm j}$ < 150 °C

Parameter	Symbol	bol Limit Values				Measuring Condition
		min.	typ.	max.		
Output voltage	V_{Q}	4.90	5.00	5.10	V	1 mA \leq $I_{\rm Q}$ \leq 100 mA; 6 V \leq $V_{\rm I}$ \leq 16 V
Output voltage	V_{Q}	4.85	5.00	5.15	V	$I_{\rm Q} \le$ 150 mA; 6 V $\le V_{\rm I} \le$ 16 V
Current limit	I_{Q}	250	400	500	mA	_
Current consumption; $I_{q} = I_{l} - I_{Q}$	I_{q}	_	65	105	μΑ	Inhibit ON; $I_{\rm Q} \leq$ 1 mA, $T_{\rm j}$ < 85 °C
Current consumption; $I_q = I_l - I_Q$	I_{q}	_	65	100	μΑ	Inhibit ON; $I_Q \le 1$ mA, $T_j = 25$ °C
Current consumption; $I_q = I_l - I_Q$	I_{q}	_	170	500	μΑ	Inhibit ON; $I_Q = 10 \text{ mA}$
Current consumption; $I_q = I_l - I_Q$	I_{q}	_	0.7	2	mA	Inhibit ON; $I_{\rm Q}$ = 50 mA
Current consumption; $I_q = I_l - I_Q$	I_{q}	_	_	1	μΑ	$V_{\overline{\text{INH}}} = 0 \text{ V};$ $T_{\text{j}} = 25 \text{ °C}$
Drop voltage	V_{dr}	_	0.22	0.5	V	$I_{\rm Q}$ = 100 mA ¹⁾
Load regulation	ΔV_{Q}	_	5	30	mV	$I_{\rm Q}$ = 1 mA to 100 mA
Line regulation	ΔV_{Q}	_	10	25	mV	$V_{\rm I}$ = 6 V to 28 V; $I_{\rm Q}$ = 1 mA
Power Supply Ripple rejection	PSRR	_	66	_	dB	$\begin{split} f_{\rm r} &= 100 \text{ Hz}; \ V_{\rm r} = 1 \ V_{\rm SS}; \\ I_{\rm Q} &= 100 \text{ mA} \end{split}$

Inhibit (TLE 4299 GM only)

Inhibit OFF voltage range	$V_{\overline{ ext{INH OFF}}}$	_	_	0.8	V	TLE 4299 GM; $V_{\rm Q}$ off
Inhibit ON voltage range	$V_{\overline{INH}ON}$	3.5	_	_	V	TLE 4299 GM; $V_{\rm Q}$ on
High input current	$I_{\overline{INH}ON}$	_	3	5	μΑ	TLE 4299 GM; $V_{\overline{\text{INH}}}$ = 5 V
Low input current	$I_{\overline{INH}OFF}$	_	0.5	2	μΑ	TLE 4299 GM; $V_{\overline{\text{INH}}}$ = 0 V

Drop voltage = $V_{\rm I} - V_{\rm Q}$ (measured when the output voltage has dropped 100 mV from the nominal value obtained at 13.5 V input.)

Data Sheet Rev. 1.0 9 2002-01-17



Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V; $T_{\rm j}$ = -40 °C < $T_{\rm j}$ < 150 °C

Parameter	Symbol	Limit Values			Unit	Measuring Condition
		min.	typ.	max.		

Reset Generator

	Ι	1	ı	T	1	Τ
Switching threshold	V_{rt}	4.50	4.60	4.80	V	_
Reset pull up	R_{RO}	10	20	40	kΩ	_
Reset low voltage	V_{R}	_	0.17	0.40	V	$V_{\rm Q}$ < 4.5 V; internal $R_{\rm RO}$; $I_{\rm R}$ = 1 mA
External reset pull up	$V_{R\;ext}$	5.6	_	_	kΩ	Pull up resistor to Q
Delay switching threshold	V_{DT}	1.5	1.85	2.2	V	-
Switching threshold	V_{ST}	0.40	0.50	0.60	V	-
Reset delay low voltage	V_{D}	_	_	0.1	V	$V_{\rm Q} < V_{\rm RT}$
Charge current	I_{ch}	4.0	8.0	12.0	μА	$V_{\rm D}$ = 1 V
Reset delay time	t_{d}	17	28	35	ms	$C_{\rm D}$ = 100 nF
Reset reaction time	$t_{\rm rr}$	0.5	1.2	3.0	μS	$C_{\rm D}$ = 100 nF
Reset adjust switching threshold	$V_{ m RADJTH}$	1.26	1.36	1.44	V	V _Q > 3.5 V

Input Voltage Sense

Sense threshold high	$V_{SI\;high}$	1.34	1.45	1.54	V	_
Sense threshold low	V_{SIlow}	1.26	1.36	1.44	V	_
Sense input switching hysteresis	V_{SIHYST}	50	90	130	mV	$V_{\rm SIHYST} = V_{\rm SIhigh} - V_{\rm SIlow}$
Sense output low voltage	V_{SOlow}	_	0.1	0.4	V	$V_{\rm SI}$ < 1.20 V; $V_{\rm i}$ > 4.2 V; $I_{\rm SO}$ = 0
External SO pull up resistor	R _{SO ext}	5.6	_	_	kΩ	_
Sense pull up	R_{SO}	10	20	40	kΩ	-
Sense input current	I_{SI}	– 1	0.1	1	μА	_
Sense high reaction time	$t_{ m pd~SO~LH}$	_	2.4	2.9	μS	-
Sense low reaction time	$t_{ m pd~SO~HL}$	_	1.7	2.1	μS	_

Data Sheet Rev. 1.0 10 2002-01-17



Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at $T_A = 25$ °C and the given supply voltage.

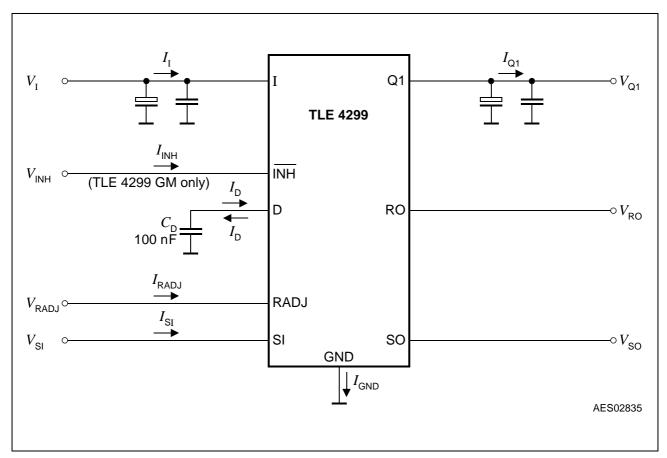


Figure 5 Measurement Circuit



Application Information

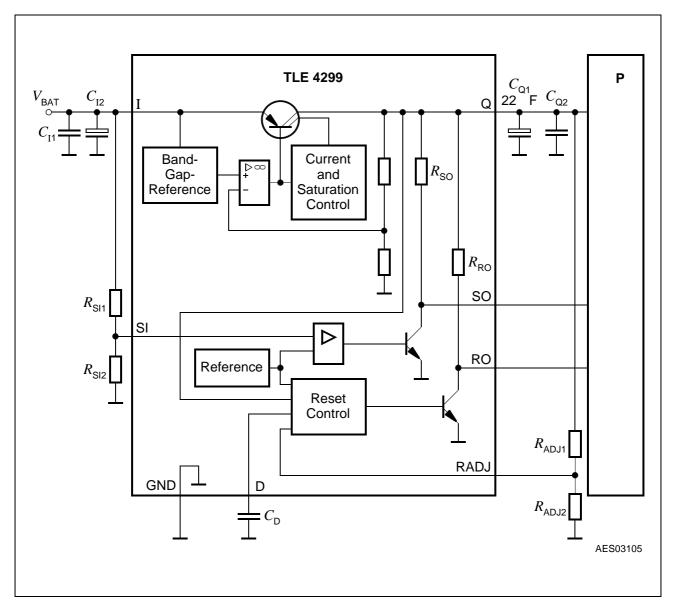


Figure 6 Application Diagram TLE 4299 G



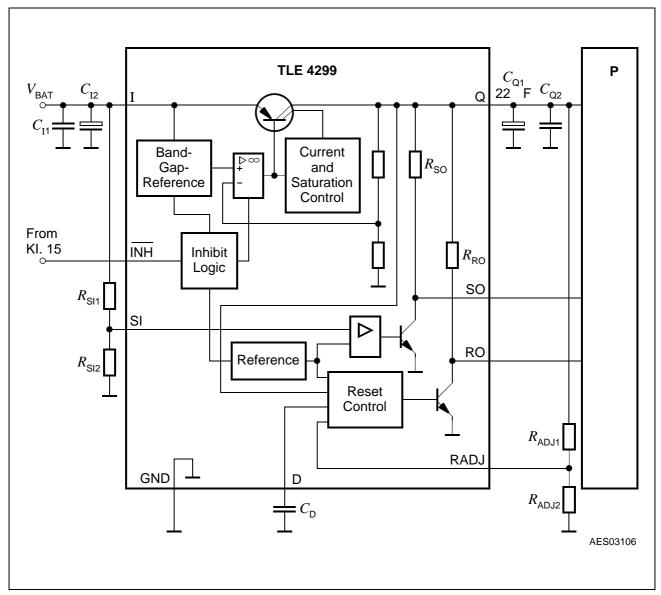


Figure 7 Application Diagram with Inhibit Function

The TLE 4299 supplies a regulated 5 V output voltage with an accuracy of 2% from an input voltage between 5.5 V and 45 V in the temperature range of $T_{\rm j}$ = - 40 to 150 °C.

The device is capable to supply 150 mA. For protection at high input voltage above 25 V, the output current is reduced (SOA protection).

An input capacitor is necessary for compensating line influences and to limit steep input edges. A resistor of approx. 1 Ω in series with $C_{\rm I}$, can damp the LC of the input inductivity and the input capacitor.

The voltage regulator requires for stability an output capacitor C_Q of at least 22 μF with an ESR below 5 Ω .



Reset

The power on reset feature is necessary for a defined start of the microprocessor when switching on the application. For the reset delay time after the output voltage of the regulator is above the reset threshold, the reset signal is set High again. The reset delay time is defined by the reset delay capacitor $C_{\rm D}$ at pin D.

The under-voltage reset circuitry supervises the output voltage. In case $V_{\rm Q}$ decreases below the reset threshold the reset output is set LOW after the reset reaction time. The reset LOW signal is generated down to an output voltage $V_{\rm Q}$ to 1 V. Both the reset reaction time and the reset delay time is defined by the capacitor value.

The power on reset delay time is defined by the charging time of an external delay capacitor $C_{\rm D}$.

$$C_{\rm D} = (t_{\rm d} \times I_{\rm D}) / \Delta V \tag{1}$$

With

 C_{D} reset delay capacitor

 $t_{\rm d}$ reset delay time

 $\Delta V = V_{UD}$, typical 1.8 V for power up reset

 $\Delta V = V_{\text{LD}} - V_{\text{LD}}$ typical 1.35 V for undervoltage reset

 $I_{\rm D}$ charge current typical 6.5 μ A

For a delay capacitor $C_{\rm D}$ =100 nF the typical power on reset delay time is 28 ms.

The reset reaction time $t_{\rm RR}$ is the time it takes the voltage regulator to set reset output LOW after the output voltage has dropped below the reset threshold. It is typically 1 μ s for delay capacitor of 100 nF. For other values for $C_{\rm D}$ the reaction time can be estimated using the following equation:

$$t_{\rm RR} = 10 \text{ ns / nF} \times C_{\rm D}$$
 [2]



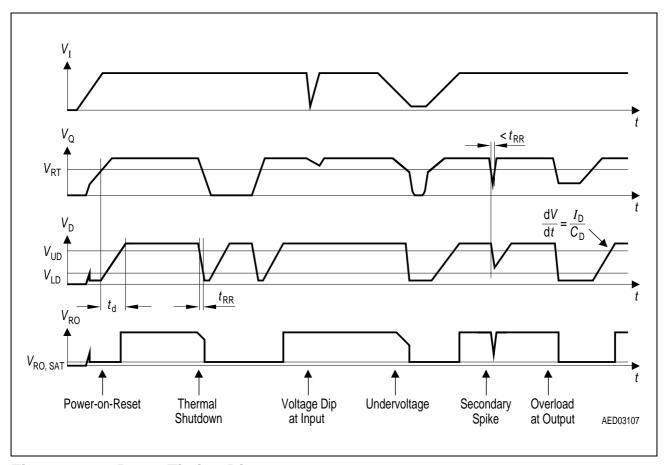


Figure 8 Reset Timing Diagram

The reset output is an open collector output with a pull-up resistor of typical 20 k Ω to Q. An external pull-up can be added with a resistor value of at least 5.6 k Ω .

In addition the reset switching threshold can be adjusted by an external voltage divider. The feature is useful for microprocessors which guarantee safe operation down to voltages below the internally set reset threshold of 4.65 V typical.

If the internal used reset threshold of typical 4.65 V is used, the pin RADJ has to be connected to GND.

If a lower reset threshold is required by the system, a voltage divider defines the reset threshold $V_{\rm Rth}$ between 3.5 V and 4.60 V:

$$V_{\mathsf{Rth}} = V_{\mathsf{RADJTH}} \times (R_{\mathsf{ADJ1}} + R_{\mathsf{ADJ2}}) / R_{\mathsf{ADJ2}}$$
 [3]

 $V_{\mathsf{RADJ\,TH}}$ is typical 1.36 V.



Early Warning

The early warning function compares a voltage defined by the user to an internal reference voltage. Therefore the supervised voltage has to be scaled down by an external voltage divider in order to compare it to the internal sense threshold of typical 1.35 V. The sense output pin is set low, when the voltage at SI falls below this threshold.

A typical example where the circuit can be used is to supervise the input voltage $V_{\rm I}$ to give the microcontroller a prewarning of low battery condition.

Calculation to the voltage divider can be easily done since the sense input current can be neglected.

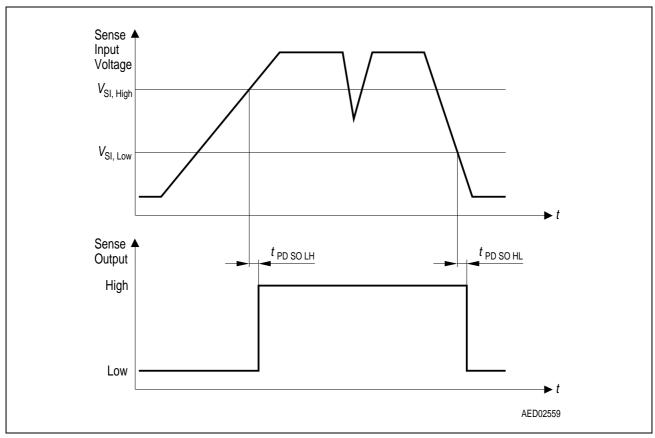


Figure 9 Sense Timing Diagram

$$V_{\text{thHL}} = (R_{\text{SI1}} + R_{\text{SI2}})/R_{\text{SI2}} \times V_{\text{SI low}}$$
 [4]

$$V_{\text{thLH}} = (R_{\text{SI1}} + R_{\text{SI2}})/R_{\text{SI2}} \times V_{\text{SI high}}$$
 [5]

The sense in comparator uses a hysteresis of typical 100 mV. This hysteresis of the supervised threshold is multiplied by the resistor dividers amplification $(R_{SI1} + R_{SI2})/R_{SI1}$.

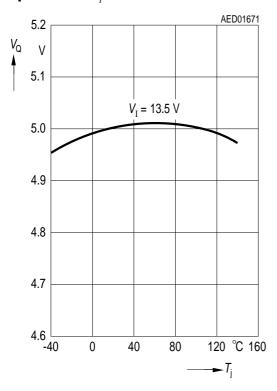
The sense in comparator can also be used for receiving data with a threshold of typical 1.35 V and a hysteresis of 100 mV. Of course also the data signal can be scaled down with a resistive divider as shown above. With a typical delay time of 2.4 μ s for positive transitions and 1.7 μ s for negative transitions receiving data of up to 100 kBaud are possible.



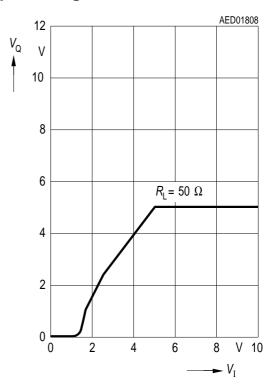
The sense output is an open collector output with a pull-up resistor of typical 20 k Ω to Q. An external pull-up can be added with a resistor value of at least 5.6 k Ω .

Typical Performance Characteristics

Output Voltage $V_{\rm Q}$ versus Temperature $T_{\rm i}$

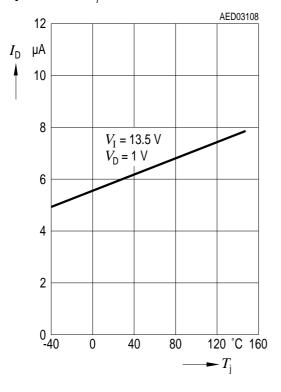


Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$

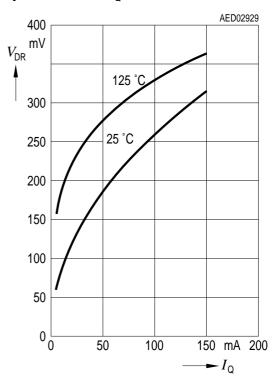




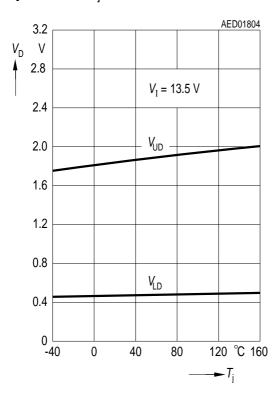
Charge Current $I_{\rm ch}$ versus Temperature $T_{\rm i}$



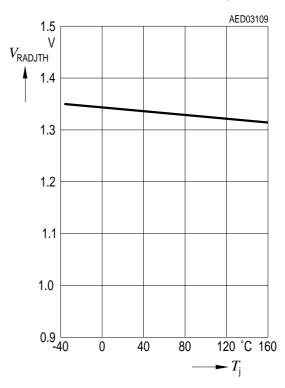
Drop Voltage $V_{\rm dr}$ versus Output Current $I_{\rm Q}$



Switching Voltage $V_{\mbox{\tiny dt}}$ and $V_{\mbox{\tiny st}}$ versus Temperature $T_{\mbox{\tiny i}}$

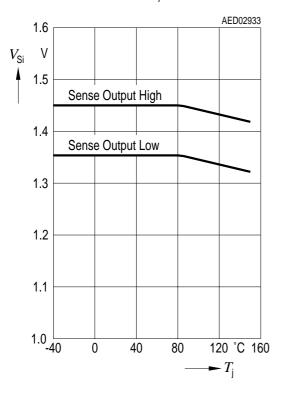


Reset Adjust Switching Threshold V_{RADJTH} versus Temperature T_{j}

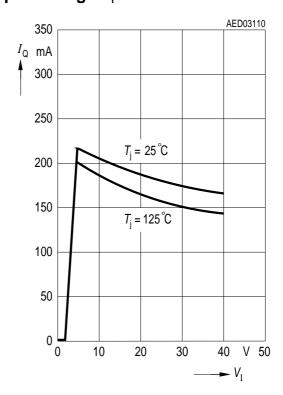




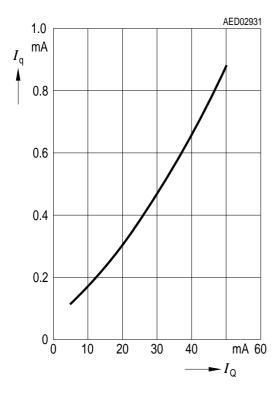
Sense Threshold $V_{\rm si}$ versus Temperature $T_{\rm i}$



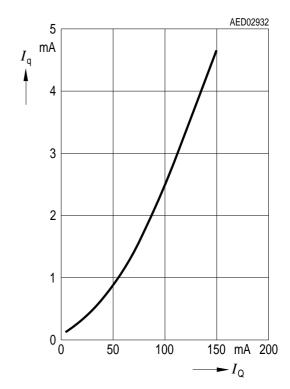
Output Current Limit $I_{\rm Q}$ versus Input Voltage $V_{\rm I}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$

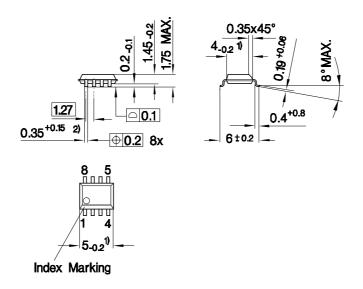




Package Outlines

P-DSO-8-3 (SMD)

(Plastic Dual Small Outline)



- 1) Does not include plastic or metal protrusion of 0.15 max. per side
- 2) Lead width can be 0.61 max. in dambar area

3PS05121

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

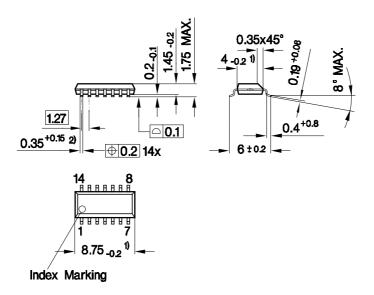
SMD = Surface Mounted Device

Dimensions in mm



P-DSO-14-8 (SMD)

(Plastic Dual Small Outline)



- 1) Does not include plastic or metal protrusion of 0.15 max. per side
- 2) Lead width can be 0.61 max. in dambar area

PS05093

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

SMD = Surface Mounted Device

Dimensions in mm



Edition 2002-01-17

Published by Infineon Technologies AG, St.-Martin-Strasse 53, D-81541 München, Germany

© Infineon Technologies AG 2002. All Rights Reserved.

Attention please!

The information herein is given to describe certain components and shall not be considered as warranted characteristics.

Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.